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Rhonda Grant

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Docket: 0756-958



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of)
Shunpei YAMAZAKI et al.)
Serial No. 08/183,800) Art Unit: 2508
Filed: January 21, 1994) Examiner: M. Saadat
For: SEMICONDUCTOR MATERIAL)
AND METHOD FOR FORMING)
THE SAME AND THIN FILM)
TRANSISTOR) Date: August 8, 1994

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AMENDMENT

Honorable Commissioner of Patents and Trademarks
Washington, D.C. 20231

8/25/94

Sir:

In response to the Office Action of April 8, 1994, please amend the subject application as follows:

IN THE CLAIMS:

Please amend claims 23, 25, and 27 as follows:

23. (Amended) A thin film transistor comprising:
a channel semiconductor layer [comprising]:
a gate insulating layer contacting said channel layer; and
a gate electrode adjacent to said channel layer with said gate

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